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3-V TO 5.5-V MULTICHANNEL RS-232 LINE DRIVER/RECEIVER WITH ±15-kV ESD (HBM) PROTECTION

SLLS710A-FEBRUARY 2006-REVISED APRIL 2006

FEATURES

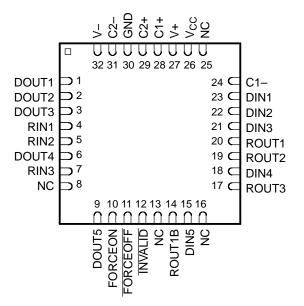
- RS-232 Bus-Pin ESD Protection Exceeds ±15 kV Using Human-Body Model (HBM)
- Meets or Exceeds the Requirements of TIA/EIA-232-F and ITU v.28 Standards
- Operates With 3-V to 5.5-V V_{CC} Supply
- Operates up to 400 kbit/s
- Five Drivers and Three Receivers
- Auto-Powerdown Plus Feature Enables Flexible Power-Down Mode
- Low Standby Current . . . 1 µA Typical
- External Capacitors . . . 4 \times 0.1 μF
- Accepts 5-V Logic Input With 3.3-V Supply
- Always-Active Noninverting Receiver Output (ROUT1B)
- Alternative High-Speed Pin-Compatible Device (1 Mbit/s) for SNx5C3238
- ESD Protection for RS-232 Interface Pins - ±15 kV – Human-Body Model (HBM)
 - $-\pm 8$ kV IEC61000-4-2, Contact Discharge
 - $-\pm$ 15 kV IEC61000-4-2, Contact Discharge

APPLICATIONS

- Battery-Powered Systems
- PDAs
- Notebooks
- Subnotebooks
- Laptops
- Palmtop PCs
- Hand-Held Equipment
- Modems
- Printers

DB, DW, OR PW PACKAGE (TOP VIEW)							
C2+ GND C2- DOUT1 DOUT2 DOUT3 RIN1 RIN2 DOUT4 RIN3 DOUT5 FORCEON	1 2 3 4 5 6 7 8 9 10 11 12 13 14	28 27 26 25 24 23 22 21 20 19 18 17 16 15	C1+ V+ V _{CC} C1- DIN1 DIN2 DIN3 ROUT1 ROUT2 DIN4 ROUT3 DIN5 ROUT1B				
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DESCRIPTION/ORDERING INFORMATION

The MAX3238E consists of five line drivers, three line receivers, and a dual charge-pump circuit with \pm 15-kV ESD (HBM) protection on the driver output (DOUT) and receiver input (RIN) terminals. The device meets the requirements of TIA/EIA-232-F and provides the electrical interface between notebook and subnotebook computer applications. The charge pump and four small external capacitors allow operation from a single 3-V to 5.5-V supply. In addition, the device includes an always-active noninverting output (ROUT1B), which allows applications using the ring indicator to transmit data while the device is powered down. This device operates at data signaling rates up to 250 kbit/s and a maximum of 30-V/ μ s driver output slew rate.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

MAX3238E 3-V TO 5.5-V MULTICHANNEL RS-232 LINE DRIVER/RECEIVER WITH $\pm 15\text{-kV}$ ESD (HBM) PROTECTION



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DESCRIPTION/ORDERING INFORMATION (CONTINUED)

Flexible control options for power management are featured when the serial port and driver inputs are inactive. The auto-powerdown plus feature functions when FORCEON is low and FORCEOFF is high. During this mode of operation, if the device does not sense valid signal transitions on all receiver and driver inputs for approximately 30 s, the built-in charge pump and drivers are powered down, reducing the supply current to 1 μ A. By disconnecting the serial port or placing the peripheral drivers off, auto-powerdown plus occurs if there is no activity in the logic levels for the driver inputs. Auto-powerdown plus can be disabled when FORCEON and FORCEOFF are high. With auto-powerdown plus enabled, the device activates automatically when a valid signal is applied to any receiver or driver input. INVALID is high (valid data) if any receiver input voltage is greater than 2.7 V or less than -2.7 V, or has been between -0.3 V and 0.3 V for less than 30 μ s. Refer to Figure 5 for receiver input levels.

T _A	PAC	CKAGE ⁽¹⁾	ORDERABLE PART NUMBER	TOP-SIDE MARKING
	SSOP – DB	Tube of 50	MAX3238ECDB	MAX3238EC
	550P - DB	Reel of 2000	MAX3238ECDBR	
0°C to 70°C	TSSOP – PW	Tube of 50	MAX3238ECPW	MP238EC
	1330F - FW	Reel of 2000	MAX3238ECPWR	WF230EC
	SOIC – DW	Reel of 2000	MAX3238ECDWR	MAX3238EC
	QFN – RHB	Reel of 2000	MAX3238ECRHBR	Preview
	SSOP – DB	Tube of 50	MAX3238EIDB	MAX3238EI
	330F - DB	Reel of 2000	MAX3238EIDBR	INIAA3230E1
40°C to 95°C	TSSOP – PW	Tube of 50	MAX3238EIPW	- MP238EI
-40 C 10 85 C	1330F - FW	Reel of 2000	MAX3238EIPWR	
	SOIC – DW	Reel of 2000	MAX3238ICDWR	MAX3238EI
	QFN – RHB	Reel of 2000	MAX3238EIRHBR	Preview

ORDERING INFORMATION

(1) Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

MAX3238E 3-V TO 5.5-V MULTICHANNEL RS-232 LINE DRIVER/RECEIVER WITH ±15-kV ESD (HBM) PROTECTION

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FUNCTION TABLES

Each Driver⁽¹⁾

		INPUTS			
DIN	FORCEON	FORCEOFF	TIME ELAPSED SINCE LAST RIN OR DIN TRANSITION	OUTPUT DOUT	DRIVER STATUS
Х	Х	L	X	Z	Powered off
L	Н	Н	X	Н	Normal operation with
Н	н	н	x	L	auto-powerdown plus disabled
L	L	Н	<30 s	Н	Normal operation with
Н	L	н	<30 s	L	auto-powerdown plus enabled
L	L	Н	>30 s	Z	Powered off by
н	L	Н	>30 s	Z	auto-powerdown plus feature

(1) H = high level, L = low level, X = irrelevant, Z = high impedance

Each Receiver⁽¹⁾

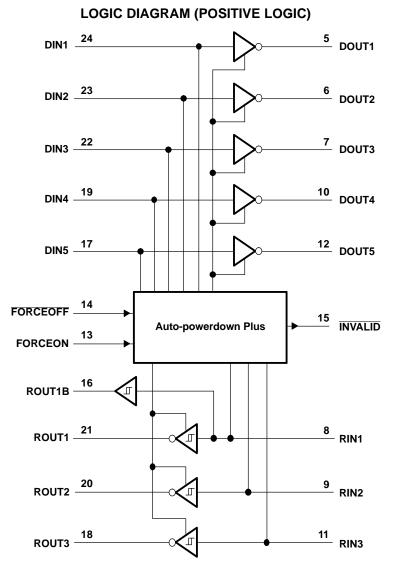
		INPUTS		OUT	PUTS	
RIN1	RIN2-RIN3	FORCEOFF	TIME ELAPSED SINCE LAST RIN OR DIN TRANSITION	ROUT1B	ROUT2 AND ROUT3	RECEIVER STATUS
L	Х	L	Х	L	Z	Powered off while
н	Х	L	х	Н	Z	ROUT1B is active
L	L	Н	<30 s	L	н	
L	н	н	<30 s	L	L	Normal operation with
Н	L	н	<30 s	Н	н	auto-powerdown plus
Н	н	н	<30 s	Н	L	disabled/enabled
Open	Open	н	<30 s	L	н	

(1) H = high level, L = low level, X = irrelevant, Z = high impedance (off), Open = input disconnected or connected driver off

MAX3238E 3-V TO 5.5-V MULTICHANNEL RS-232 LINE DRIVER/RECEIVER WITH \pm 15-kV ESD (HBM) PROTECTION



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Absolute Maximum Ratings⁽¹⁾

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V _{CC}	Supply voltage range ⁽²⁾		-0.3	6	V
V+	Positive-output supply voltage range ⁽²⁾		-0.3	7	V
V–	Negative-output supply voltage range ⁽²⁾		0.3	-7	V
V+ - V-	Supply voltage difference ⁽²⁾			13	V
V		Driver (FORCEOFF, FORCEON)	-0.3	6	V
V _I I	Input voltage range	Receiver	-25	25	v
M		Driver	-13.2	13.2	V
Vo	Output voltage range	Receiver (INVALID)	-0.3	13.2 V _{CC} + 0.3	V
		DB package		62	
0	Declare thermal impedance $(3)(4)$	DW package		46	°C/W
θ_{JA}	Package thermal impedance ⁽³⁾⁽⁴⁾	PW package		62	-C/W
		RHB package		TBD	
TJ	Operating virtual junction temperature	· · · ·		150	°C
T _{stg}	Storage temperature range		-65	150	°C

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

All voltages are with respect to network GND. (2)

Maximum power dissipation is a function of $T_{I}(max)$, θ_{IA} , and T_{A} . The maximum allowable power dissipation at any allowable ambient (3) temperature is $P_D = (T_J(max) - T_A)/\theta_{JA}$. Operating at the absolute maximum T_J of 150°C can affect reliability.

The package thermal impedance is calculated in accordance with JESD 51-7. (4)

Recommended Operating Conditions⁽¹⁾

See Figure 6

				MIN	NOM	MAX	UNIT
	Supply voltage		$V_{CC} = 3.3 V$	3	3.3	3.6	V
	upply voltage DIN, FORCEOFF, river and control high-level input voltage DIN, FORCEOFF, river and control low-level input voltage DIN, FORCEOFF, eceiver input voltage DIN, FORCEOFF,	$V_{CC} = 5 V$	4.5	5	5.5	v	
V	Driver and control high lovel input veltage	DIN, FORCEOFF,	$V_{CC} = 3.3 V$	2		5.5	V
VIH	Driver and control high-level linput voltage	FORCEON	$V_{CC} = 5 V$	2.4		5.5	v
V_{IL}	Driver and control low-level input voltage	DIN, FORCEOFF, FORC	CEON	0		0.8	V
VI	Receiver input voltage			-25		25	V
Ŧ	Operating free air temperature		MAX3238EC	0		70	°C
T _A	Operating free-air temperature		MAX3238EI	-40		85	

(1) Testing supply conditions are C1–C4 = 0.1 μ F at V_{CC} = 3.3 V ± 0.15 V; C1–C4 = 0.22 μ F at V_{CC} = 3.3 V ± 0.3 V; and C1 = 0.047 μ F and C2–C4 = 0.33 μ F at V_{CC} = 5 V ± 0.5 V.

Electrical Characteristics⁽¹⁾

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figure 6)

	PARA	METER	TEST CONDITIONS	MIN	TYP ⁽²⁾	MAX	UNIT
I _I	Input leakage current	FORCEOFF, FORCEON			±0.01	±1	μA
		Auto-powerdown plus disabled	No load, FORCEOFF and FORCEON at V_{CC}		0.5	2	mA
I _{CC}	Supply current	Powered off	No load, FORCEOFF at GND		1	10	
	(T _A = 25°C)	Auto-powerdown plus enabled	No load, FORCEOFF at V _{CC} , FORCEON at GND, All RIN are open or grounded		1	10	μA

Testing supply conditions are C1–C4 = 0.1 μ F at V_{CC} = 3.3 V ± 0.15 V; C1–C4 = 0.22 μ F at V_{CC} = 3.3 V ± 0.3 V; and C1 = 0.047 μ F at V_{CC} = 3.3 V \pm 0.3 V; and C1 = 0.047 μ F at V_{CC} = 3.3 V \pm 0.3 V; and C1 = 0.047 μ F at V_{CC} = 3.3 V \pm 0.3 V; and C1 = 0.047 μ F at V_{CC} = 3.3 V \pm 0. (1) and C2–C4 = 0.33 μ F at V_{CC} = 5 V ± 0.5 V. All typical values are at V_{CC} = 3.3 V or V_{CC} = 5 V, and T_A = 25°C.

(2)

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DRIVER SECTION

Electrical Characteristics⁽¹⁾

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figure 6)

	PARAMETER	TE	ST CONDITIONS	6	MIN	TYP ⁽²⁾	MAX	UNIT
V _{OH}	High-level output voltage	All DOUT at $R_L = 3 \ k\Omega$ to	GND		5	5.4		V
V _{OL}	Low-level output voltage	All DOUT at $R_L = 3 \ k\Omega$ to	GND		-5	-5.4		V
I _{IH}	High-level input current	$V_{I} = V_{CC}$				±0.01	±1	μA
I	Low-level input current	V _I at GND				±0.01	±1	μΑ
	Short-circuit output current ⁽³⁾	V _{CC} = 3.6 V,	$V_{O} = 0 V$			±35	±60	mA
I _{OS}	Short-circuit output current	V _{CC} = 5.5 V,	$V_0 = 0 V$			±40	±100	ША
r _o	Output resistance	V_{CC} , V+, and V- = 0 V,	$V_0 = \pm 2 V$		300	10M		Ω
		FORCEOFF = GND	$V_0 = \pm 12 V$,	V_{CC} = 3 V to 3.6 V			±25	۸
I _{OZ}	Output leakage current	FURGEUFF = GND	$V_{O} = \pm 10 V$,	V_{CC} = 4.5 V to 5.5 V			±25	μA

(1) Testing supply conditions are C1–C4 = 0.1 μ F at V_{CC} = 3.3 V ± 0.15 V; C1–C4 = 0.22 μ F at V_{CC} = 3.3 V ± 0.3 V; and C1 = 0.047 μ F and C2–C4 = 0.33 μ F at V_{CC} = 5 V ± 0.5 V.

(2) All typical values are at $V_{CC} = 3.3$ V or $V_{CC} = 5$ V, and $T_A = 25^{\circ}C$.

(3) Short-circuit durations should be controlled to prevent exceeding the device absolute power dissipation ratings, and not more than one output should be shorted at a time.

Switching Characteristics⁽¹⁾

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figure 6)

	PARAMETER	TEST	CONDITIONS	MIN	TYP ⁽²⁾	MAX	UNIT
	Maximum data rate	C _L = 1000 pF, One DOUT switching,	R _L = 3 kΩ, See Figure 1	250	400		kbit/s
t _{sk(p)}	Pulse skew ⁽³⁾	C _L = 150 pF to 2500 pF, See Figure 2	$R_L = 3 k\Omega$ to 7 k Ω ,		100		ns
SR(tr)	Slew rate, transition region	V _{CC} = 3.3 V,	$C_{L} = 150 \text{ pF} \text{ to } 1000 \text{ pF}$	6		30	V/µs
35(11)	(see Figure 1)	$R_L = 3 k\Omega$ to 7 k Ω	$C_{L} = 150 \text{ pF} \text{ to } 2500 \text{ pF}$	4		30	v/µs

(1) Testing supply conditions are C1–C4 = 0.1 μ F at V_{CC} = 3.3 V ± 0.15 V; C1–C4 = 0.22 μ F at V_{CC} = 3.3 V ± 0.3 V; and C1 = 0.047 μ F and C2–C4 = 0.33 μ F at V_{CC} = 5 V ± 0.5 V.

(2) All typical values are at $V_{CC} = 3.3$ V or $V_{CC} = 5$ V, and $T_A = 25^{\circ}$ C.

(3) Pulse skew is defined as $|t_{PLH} - t_{PHL}|$ of each channel of the same device.

ESD Protection

PARAMETER	TEST CONDITIONS	TYP	UNIT
	HBM	±15	
DOUT	IEC 61000-4-2, Air-Gap Discharge	±15	kV
	IEC 61000-4-2, Contact Discharge	±8	

RECEIVER SECTION

Electrical Characteristics⁽¹⁾

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figure 6)

	PARAMETER	TEST CONDITIONS	MIN	TYP ⁽²⁾	MAX	UNIT
V _{OH}	High-level output voltage	$I_{OH} = -1 \text{ mA}$	$V_{CC} - 0.6$	V _{CC} – 0.1		V
V _{OL}	Low-level output voltage	I _{OL} = 1.6 mA			0.4	V
V	Desitive going input threshold voltage	$V_{CC} = 3.3 V$		1.5	2.4	V
V _{IT+}	Positive-going input threshold voltage	$V_{CC} = 5 V$		1.8	2.4	v
V	Negative going input threshold voltage	$V_{CC} = 3.3 V$	0.6	1.2		V
V _{IT-}	Negative-going input threshold voltage	$V_{CC} = 5 V$	0.8	1.5		v
V _{hys}	Input hysteresis (V _{IT+} – V _{IT} –)			0.3		V
I _{OZ}	Output leakage current (except ROUT1B)	FORCEOFF = 0 V		±0.05	±10	μA
r _i	Input resistance	$V_{I} = \pm 3 \text{ V to } \pm 25 \text{ V}$	3	5	7	kΩ

(1) Testing supply conditions are C1–C4 = 0.1 μ F at V_{CC} = 3.3 V \pm 0.15 V; C1–C4 = 0.22 μ F at V_{CC} = 3.3 V \pm 0.3 V; and C1 = 0.047 μ F at V_{CC} = 3.3 V \pm 0.3 V; and C1 = 0.047 μ F at V_{CC} = 3.3 V \pm 0.15 V; C1–C4 = 0.22 μ F at V_{CC} = 3.3 V \pm 0.3 V; and C1 = 0.047 μ F at V_{CC} = 3.3 V \pm 0.15 V; C1–C4 = 0.22 μ F at V_{CC} = 3.3 V \pm 0.15 V; C1–C4 = 0.22 μ F at V_{CC} = 3.3 V \pm 0.15 V; C1–C4 = 0.22 μ F at V_{CC} = 3.3 V \pm 0.15 V; C1–C4 = 0.22 μ F at V_{CC} = 3.3 V \pm 0.15 V; C1–C4 = 0.22 μ F at V_{CC} = 3.3 V \pm 0.15 V; C1–C4 = 0.22 μ F at V_{CC} = 3.3 V \pm 0.15 V; C1–C4 = 0.22 μ F at V_{CC} = 3.3 V \pm 0.15 V; C1–C4 = 0.22 μ F at V_{CC} = 3.3 V \pm 0.15 V; C1–C4 = 0.22 μ F at V_{CC} = 3.3 V \pm 0.15 V; C1–C4 = 0.22 μ F at V_{CC} = 3.3 V \pm 0.3 V; and C1 = 0.047 μ F at V_{CC} = 3.3 V \pm 0.15 V; C1–C4 = 0.22 μ F at V_{CC} = 3.3 V \pm 0.15 V; C1–C4 = 0.22 μ F at V_{CC} = 3.3 V \pm 0.15 V; C1–C4 = 0.22 μ F at V_{CC} = 3.3 V \pm 0.15 V; C1–C4 = 0.22 μ F at V_{CC} = 3.3 V \pm 0.15 V; C1–C4 = 0.22 μ F at V_{CC} = 3.3 V \pm 0.15 V; C1–C4 = 0.22 μ F at V_{CC} = 3.3 V \pm 0.15 V; C1–C4 = 0.24 μ F at V_{CC} = 3.3 V \pm 0.15 V; C1–C4 = 0.24 μ F at V_{CC} = 3.3 V \pm 0.15 V; C1–C4 = 0.24 μ F at V_{CC} = 3.3 V \pm 0.15 V; C1–C4 = 0.24 μ F at V_{CC} = 3.3 V \pm 0.3 V; and C1 = 0.047 μ F at V_{CC} = 3.3 V \pm 0.15 V; C1–C4 = 0.24 μ F at V_{CC} = 3.3 V \pm 0.3 V; and C1 = 0.047 μ F at V_{CC} = 3.3 V \pm 0.15 V; C1–C4 = 0.24 μ F at V_{CC} = 3.3 V \pm 0.15 V; C1–C4 = 0.24 μ F at V_{CC} = 3.3 V \pm 0.15 V; C1–C4 = 0.24 μ F at V_{CC} = 3.3 V \pm 0.15 V; C1–C4 = 0.24 μ F at V_{CC} = 3.3 V \pm 0.15 V; C1–C4 = 0.24 μ F at V_{CC} = 3.3 V \pm 0.15 V; C1–C4 = 0.24 μ F at V_{CC} = 3.3 V \pm 0.15 V; C1–C4 = 0.24 μ F at V_{CC} = 3.3 V \pm 0.15 V; C1–C4 = 0.24 μ F at V_{CC} = 3.3 V \pm 0.15 V; C1–C4 = 0.24 μ F at V_{CC} = 3.3 V \pm 0.15 V; C1–C4 = 0.24 μ F at V_{CC} = 3.3 V \pm 0.15 V; C1–C4 = 0.24 μ F at V_{CC} = 3.3 V \pm 0.15 V; C1–C4 = 0.24 μ F at V_{CC} = 3.3 V \pm 0.15 V; C1–C4 = 0.24 μ F at V_{CC} = 3.3 and C2–C4 = 0.33 μ F at V_{CC} = 5 V ± 0.5 V. All typical values are at V_{CC} = 3.3 V or V_{CC} = 5 V, and T_A = 25°C.

(2)

Switching Characteristics⁽¹⁾

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	TYP ⁽²⁾	UNIT
t _{PLH}	Propagation delay time, low- to high-level output	C _L = 150 pF, See Figure 3	150	ns
t _{PHL}	Propagation delay time, high- to low-level output	C _L = 150 pF, See Figure 3	150	ns
t _{en}	Output enable time	$C_L = 150 \text{ pF}, R_L = 3 \text{ k}\Omega$, See Figure 4	200	ns
t _{dis}	Output disable time	$C_L = 150 \text{ pF}, R_L = 3 \text{ k}\Omega$, See Figure 4	200	ns
t _{sk(p)}	Pulse skew ⁽³⁾	See Figure 3	50	ns

Testing supply conditions are C1–C4 = 0.1 μ F at V_{CC} = 3.3 V ± 0.15 V; C1–C4 = 0.22 μ F at V_{CC} = 3.3 V ± 0.3 V; and C1 = 0.047 μ F and C2–C4 = 0.33 μ F at V_{CC} = 5 V ± 0.5 V. (1)

(2) All typical values are at $V_{CC} = 3.3$ V or $V_{CC} = 5$ V, and $T_A = 25^{\circ}C$. (3) Pulse skew is defined as $|t_{PLH} - t_{PHL}|$ of each channel of the same device.

ESD Protection

PARAMETER	TEST CONDITIONS	TYP	UNIT
	НВМ	±15	
RIN	IEC 61000-4-2, Air-Gap Discharge	±15	kV
	IEC 61000-4-2, Contact Discharge	±8	

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AUTO-POWERDOWN PLUS SECTION

Electrical Characteristics

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figure 5)

	PARAMETER	TEST CONDITIONS	MIN	MAX	UNIT
$V_{\text{T+(valid)}}$	Receiver input threshold for INVALID high-level output voltage	FORCEON = GND, $\overline{\text{FORCEOFF}} = V_{CC}$		2.7	V
V _{T-(valid)}	Receiver input threshold for INVALID high-level output voltage	FORCEON = GND, $\overline{FORCEOFF} = V_{CC}$	-2.7		V
V _{T(invalid)}	Receiver input threshold for INVALID low-level output voltage	FORCEON = GND, $\overline{FORCEOFF} = V_{CC}$	-0.3	0.3	V
V _{OH}	INVALID high-level output voltage	$I_{OH} = -1 \text{ mA}$, FORCEON = GND, FORCEOFF = V_{CC}	V _{CC} - 0.6		V
V _{OL}	INVALID low-level output voltage	I_{OL} = 1.6 mA, FORCEON = GND, FORCEOFF = V _{CC}		0.4	V

Switching Characteristics

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figure 5)

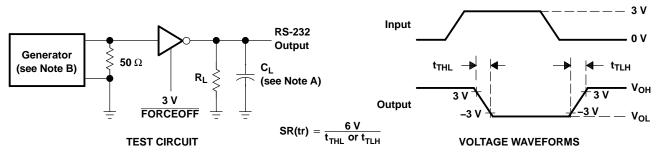
	PARAMETER	MIN	TYP ⁽¹⁾	MAX	UNIT
t _{valid}	Propagation delay time, low- to high-level output		0.1		μs
t _{invalid}	Propagation delay time, high- to low-level output		50		μs
t _{en}	Supply enable time		25		μs
t _{dis}	Receiver or driver edge to auto-powerdown plus	15	30	60	S

(1) All typical values are at V_{CC} = 3.3 V or V_{CC} = 5 V, and T_A = 25 ^{\circ}C.

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PARAMETER MEASUREMENT INFORMATION



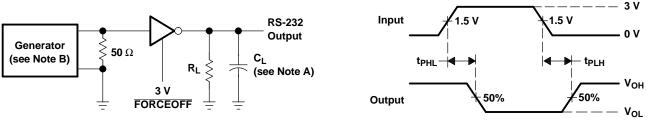
A. C_L includes probe and jig capacitance.

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B. The pulse generator has the following characteristics: PRR = 250 kbit/s, $Z_O = 50 \Omega$, 50% duty cycle, $t_r \le 10$ ns, $t_f \le 10$ ns.

Figure 1. Driver Slew Rate

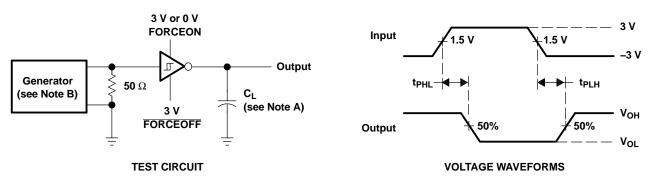


TEST CIRCUIT

VOLTAGE WAVEFORMS

- A. C_L includes probe and jig capacitance.
- B. The pulse generator has the following characteristics: PRR = 250 kbit/s, $Z_O = 50 \Omega$, 50% duty cycle, $t_r \le 10$ ns, $t_f \le 10$ ns.

Figure 2. Driver Pulse Skew

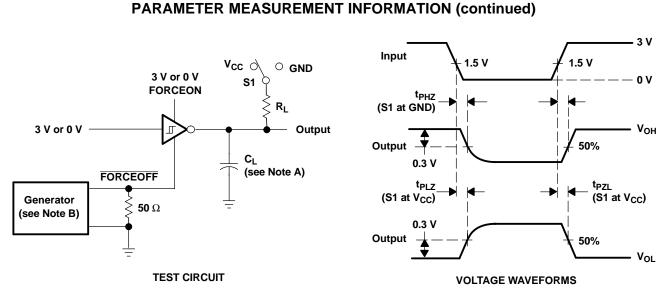


- A. C_L includes probe and jig capacitance.
- B. The pulse generator has the following characteristics: $Z_O = 50 \ \Omega$, 50% duty cycle, $t_r \le 10 \text{ ns}$, $t_f \le 10 \text{ ns}$.

Figure 3. Receiver Propagation Delay Times

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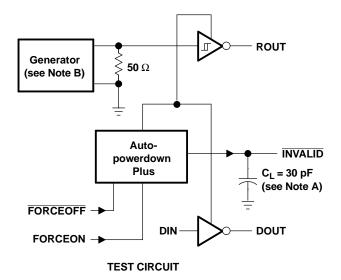
- A. C_L includes probe and jig capacitance.
- B. The pulse generator has the following characteristics: $Z_O = 50 \ \Omega$, 50% duty cycle, $t_r \le 10 \text{ ns}$.
- C. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
- D. t_{PZL} and t_{PZH} are the same as t_{en} .

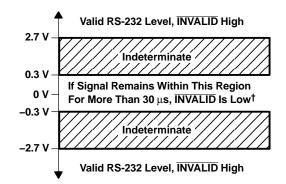
Figure 4. Receiver Enable and Disable Times

MAX3238E 3-V TO 5.5-V MULTICHANNEL RS-232 LINE DRIVER/RECEIVER WITH ±15-kV ESD (HBM) PROTECTION

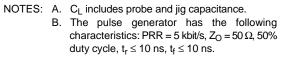
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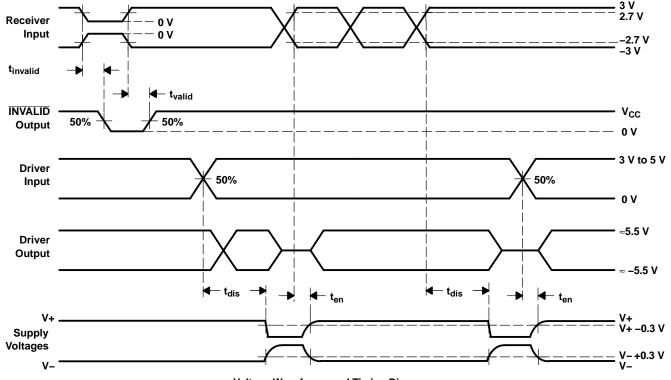
PARAMETER MEASUREMENT INFORMATION (continued)





 † Auto-powerdown plus disables drivers and reduces supply current to 1 $\mu A.$





Voltage Waveforms and Timing Diagrams

Figure 5. INVALID Propagation-Delay Times and Supply-Enabling Time

MAX3238E 3-V TO 5.5-V MULTICHANNEL RS-232 LINE DRIVER/RECEIVER WITH \pm 15-kV ESD (HBM) PROTECTION

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APPLICATION INFORMATION

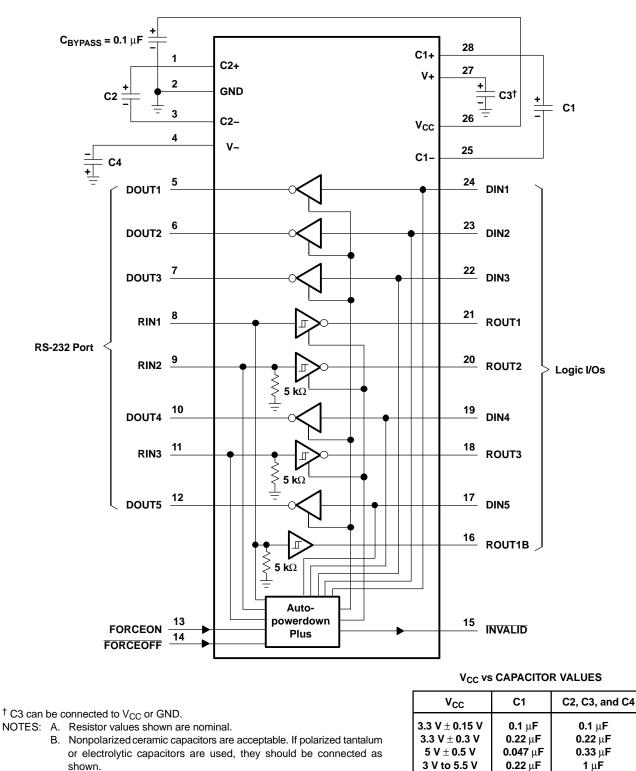


Figure 6. Typical Operating Circuit and Capacitor Values



PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
	(1)		Diamig		۹.,	(2)	(6)	(3)		(4/3)	
MAX3238ECDBR	ACTIVE	SSOP	DB	28	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	MAX3238EC	Samples
MAX3238ECDWR	ACTIVE	SOIC	DW	28	1000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	MAX3238EC	Samples
MAX3238ECPWR	ACTIVE	TSSOP	PW	28	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	MP238EC	Samples
MAX3238EIDBR	ACTIVE	SSOP	DB	28	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	MAX3238EI	Samples
MAX3238EIDWR	ACTIVE	SOIC	DW	28	1000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	MAX3238EI	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

⁽⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.



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PACKAGE OPTION ADDENDUM

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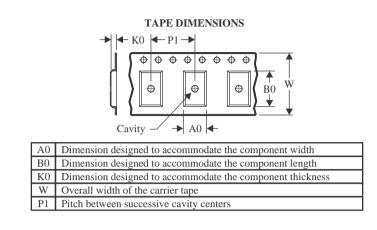


Texas

STRUMENTS

TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
MAX3238ECDBR	SSOP	DB	28	2000	330.0	16.4	8.2	10.5	2.5	12.0	16.0	Q1
MAX3238ECDWR	SOIC	DW	28	1000	330.0	32.4	11.35	18.67	3.1	16.0	32.0	Q1
MAX3238ECPWR	TSSOP	PW	28	2000	330.0	16.4	6.9	10.2	1.8	12.0	16.0	Q1
MAX3238EIDBR	SSOP	DB	28	2000	330.0	16.4	8.2	10.5	2.5	12.0	16.0	Q1
MAX3238EIDWR	SOIC	DW	28	1000	330.0	32.4	11.35	18.67	3.1	16.0	32.0	Q1



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PACKAGE MATERIALS INFORMATION

5-Dec-2023



Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
MAX3238ECDBR	SSOP	DB	28	2000	356.0	356.0	35.0
MAX3238ECDWR	SOIC	DW	28	1000	350.0	350.0	66.0
MAX3238ECPWR	TSSOP	PW	28	2000	356.0	356.0	35.0
MAX3238EIDBR	SSOP	DB	28	2000	356.0	356.0	35.0
MAX3238EIDWR	SOIC	DW	28	1000	350.0	350.0	66.0

DW (R-PDSO-G28)

PLASTIC SMALL OUTLINE



NOTES:

A. All linear dimensions are in inches (millimeters). Dimensioning and tolerancing per ASME Y14.5M-1994.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).

D. Falls within JEDEC MS-013 variation AE.



LAND PATTERN DATA



NOTES:

A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Refer to IPC7351 for alternate board design.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



PW (R-PDSO-G28)

PLASTIC SMALL OUTLINE



NOTES:

A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
B. This drawing is subject to change without notice.

Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.

Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.

E. Falls within JEDEC MO-153



DB0028A



PACKAGE OUTLINE

SSOP - 2 mm max height

SMALL OUTLINE PACKAGE



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-150.



DB0028A

EXAMPLE BOARD LAYOUT

SSOP - 2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



DB0028A

EXAMPLE STENCIL DESIGN

SSOP - 2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

9. Board assembly site may have different recommendations for stencil design.



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